

Code No: R05210404

R05**Set No. 2**

II B.Tech I Semester Examinations, November 2010

ELECTRONIC CIRCUIT ANALYSIS**Common to Electronics And Telematics, Electronics And Communication Engineering****Time: 3 hours****Max Marks: 80****Answer any FIVE Questions
All Questions carry equal marks**

1. (a) What are the main advantages of class-C operating mode in RF applications?
(b) Draw the circuit of class-C radio frequency amplifier and explain its operation with necessary waveforms? [8+8]
2. For the circuit shown in figure 3:
 - (a) Draw the small signal equivalent circuit.
 - (b) Derive Voltage gain (A_V).
 - (c) Derive the expression for resonant frequency.
 - (d) Voltage gain at resonant frequency (A_{res}).
 - (e) Quality factor of the resonant circuit. [16]

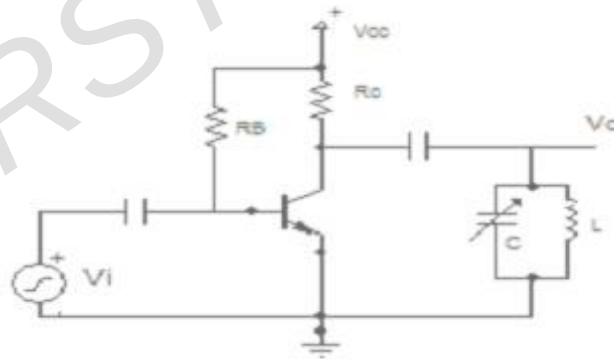


Figure 3

3. (a) Explain why voltage regulators are required for a DC power supply operating from an AC source?
(b) A power supply has a voltage regulation of 1%. If the no load voltage is 30V. What is the full load voltage?
(c) Give the differences between Load and Line Regulations. [6+4+6]
4. (a) Using three pin voltage regulator, design a current source that will deliver 0.25A current to 48 ohms 10W load. From data sheet $I_Q = 4.2$ mA and $V_R = 5$ V [6]
(b) Compare IC 723 and IC78XX Voltage Regulators [4]
(c) What is UPS and explain how it differs from regulated power supply? [6]

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5. (a) Sketch the circuit of a Common Source amplifier. Derive an expression for the Voltage gain at low frequencies. What is the maximum value of A_V .
- (b) Calculate the voltage gain $A_V = V_o / V_i$ at 1KHz for the circuit shown 7b. The FET parameters are $g_m = 2 \text{ mA}$ and $r_d = 10 \text{ K}$. Neglect capacitances. If the capacitance $0.003 \mu\text{F}$ is also considered, calculate the voltage gain.

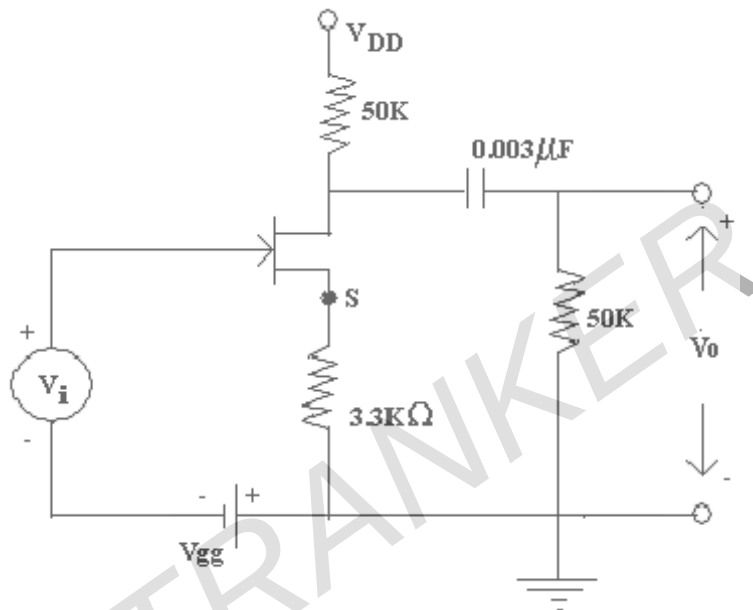


Figure 7b

6. (a) When 2-stages of identical amplifiers are cascaded, obtain the expressions for overall voltage gain, current gain and power gain.
- (b) Four identical cascaded stages have an overall upper 3-dB frequency of 20 KHz and a lower 3-dB frequency of 20 Hz. What are f_L and f_H of each stage? Assume non interacting stages? [8+8]
7. (a) Define thermal resistance of a power BJT.
- (b) A transistor with a maximum junction temperature specification of 150°C dissipates a maximum power of 40 watts at a case temperature of 25°C and 2 watts at an ambient temperature of 25°C . Find
- The thermal resistance between the junction and the case.
 - The thermal resistance between the junction and ambient.
 - Maximum power dissipation capability for safe operation in free space at a temperature of 50°C . [4+4x3]
8. (a) Define f_β . What is its relationship with f_T ? Show that in a transistor in CE configuration, show that the current gain is dependent on diffusion and transistion capacitances.
- (b) In transistor common emitter amplifier with a resistive load R_L , show that the voltage gain is $-g_m R_L$. (Use Hybrid - π model). [8+8]

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R05**Set No. 4**

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All Questions carry equal marks**

1. (a) Define thermal resistance of a power BJT.
- (b) A transistor with a maximum junction temperature specification of 150°C dissipates a maximum power of 40 watts at a case temperature of 25°C and 2 watts at an ambient temperature of 25°C . Find
 - i. The thermal resistance between the junction and the case.
 - ii. The thermal resistance between the junction and ambient.
 - iii. Maximum power dissipation capability for safe operation in free space at a temperature of 50°C . [4+4x3]
2. For the circuit shown in figure 3:
 - (a) Draw the small signal equivalent circuit.
 - (b) Derive Voltage gain (A_V).
 - (c) Derive the expression for resonant frequency.
 - (d) Voltage gain at resonant frequency (A_{res}).
 - (e) Quality factor of the resonant circuit. [16]

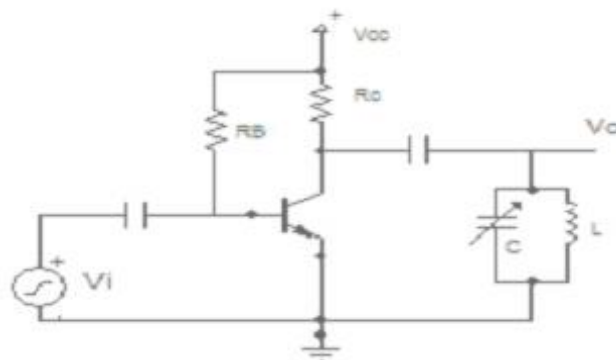


Figure 3

3. (a) Sketch the circuit of a Common Source amplifier. Derive an expression for the Voltage gain at low frequencies. What is the maximum value of A_V .
- (b) Calculate the voltage gain $A_V = V_o / V_i$ at 1KHz for the circuit shown 7b. The FET parameters are $g_m = 2 \text{ mA}$ and $r_d = 10\text{K}$. Neglect capacitances. If the capacitance $0.003 \mu\text{F}$ is also considered, calculate the voltage gain.

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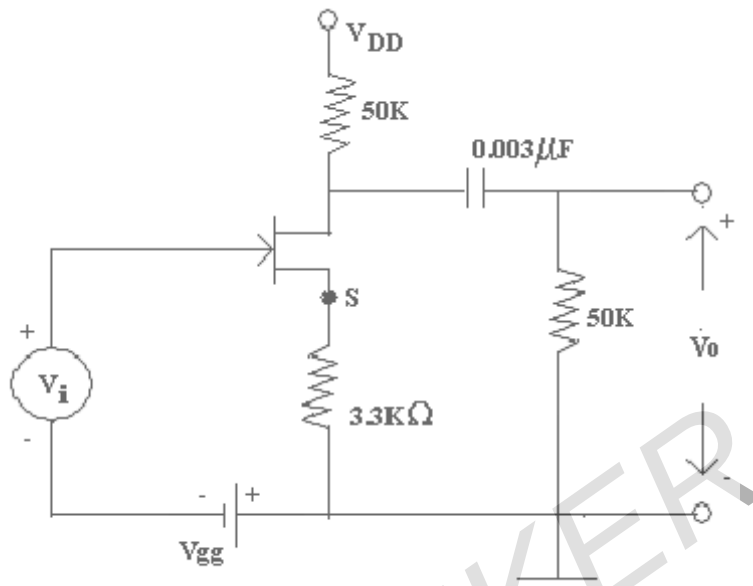
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Figure 7b

4. (a) Explain why voltage regulators are required for a DC power supply operating from an AC source?
 (b) A power supply has a voltage regulation of 1%. If the no load voltage is 30V. What is the full load voltage?
 (c) Give the differences between Load and Line Regulations. [6+4+6]
5. (a) What are the main advantages of class-C operating mode in RF applications?
 (b) Draw the circuit of class-C radio frequency amplifier and explain its operation with necessary waveforms? [8+8]
6. (a) When 2-stages of identical amplifiers are cascaded, obtain the expressions for overall voltage gain, current gain and power gain.
 (b) Four identical cascaded stages have an overall upper 3-dB frequency of 20 KHz and a lower 3-dB frequency of 20 Hz. What are f_L and f_H of each stage? Assume non interacting stages? [8+8]
7. (a) Using three pin voltage regulator, design a current source that will deliver 0.25A current to 48 ohms 10W load. From data sheet $I_Q = 4.2$ mA and $V_R = 5$ V [6]
 (b) Compare IC 723 and IC78XX Voltage Regulators [4]
 (c) What is UPS and explain how it differs from regulated power supply? [6]
8. (a) Define f_β . What is its relationship with f_T ? Show that in a transistor in CE configuration, show that the current gain is dependent on diffusion and transition capacitances.
 (b) In transistor common emitter amplifier with a resistive load R_L , show that the voltage gain is $-g_m R_L$. (Use Hybrid - π model). [8+8]

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FIRSTRANKER

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ELECTRONIC CIRCUIT ANALYSIS

Common to Electronics And Telematics, Electronics And Communication Engineering

Time: 3 hours

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- Sketch the circuit of a Common Source amplifier. Derive an expression for the Voltage gain at low frequencies. What is the maximum value of A_V .
 - Calculate the voltage gain $A_V = V_o / V_i$ at 1KHz for the circuit shown 7b. The FET parameters are $g_m = 2 \text{ mA}$ and $r_d = 10 \text{ K}$. Neglect capacitances. If the capacitance $0.003 \mu\text{F}$ is also considered, calculate the voltage gain.

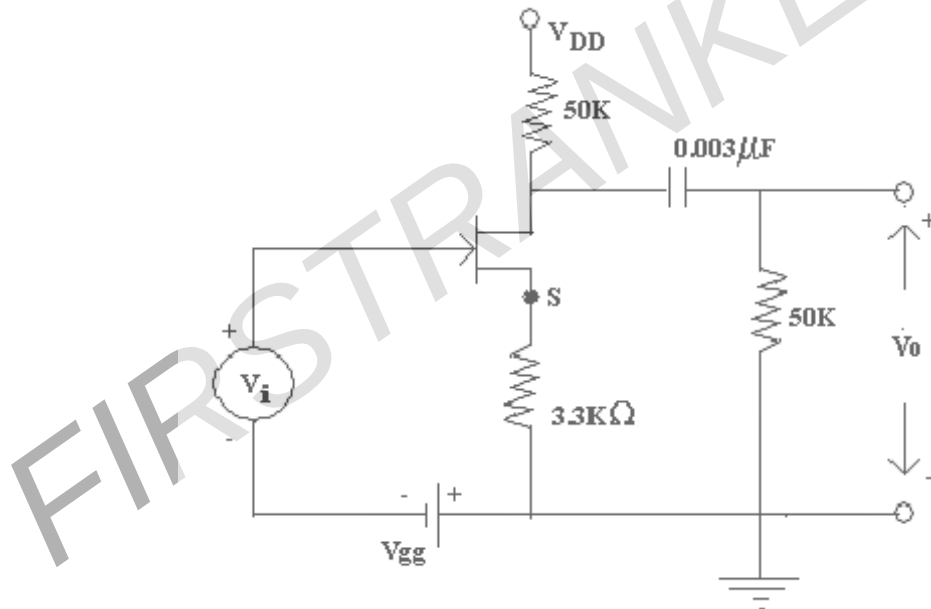


Figure 7b

- Define f_β . What is its relationship with f_T ? Show that in a transistor in CE configuration, show that the current gain is dependent on diffusion and transition capacitances.
 - In transistor common emitter amplifier with a resistive load R_L , show that the voltage gain is $-g_m R_L$. (Use Hybrid - π model). [8+8]
- What are the main advantages of class-C operating mode in RF applications?
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- Define thermal resistance of a power BJT.
 - A transistor with a maximum junction temperature specification of 150°C dissipates a maximum power of 40 watts at a case temperature of 25°C and 2 watts at an ambient temperature of 25°C . Find

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- i. The thermal resistance between the junction and the case.
 - ii. The thermal resistance between the junction and ambient.
 - iii. Maximum power dissipation capability for safe operation in free space at a temperature of 50°C . [4+4x3]
5. (a) Explain why voltage regulators are required for a DC power supply operating from an AC source?
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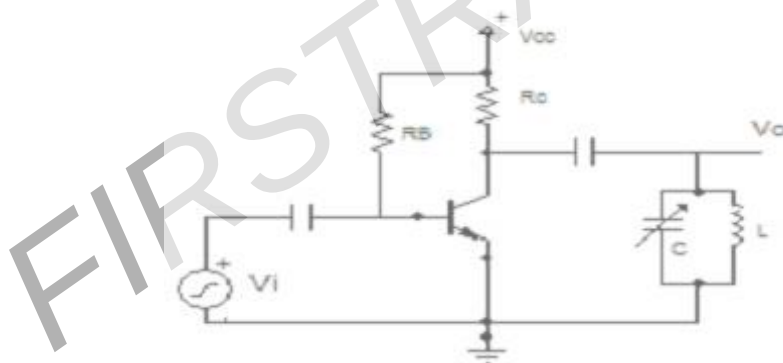


Figure 3

7. (a) Using three pin voltage regulator, design a current source that will deliver 0.25A current to 48 ohms 10W load. From data sheet $I_Q = 4.2 \text{ mA}$ and $V_R = 5\text{V}$ [6]
- (b) Compare IC 723 and IC78XX Voltage Regulators [4]
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R05**Set No. 3**

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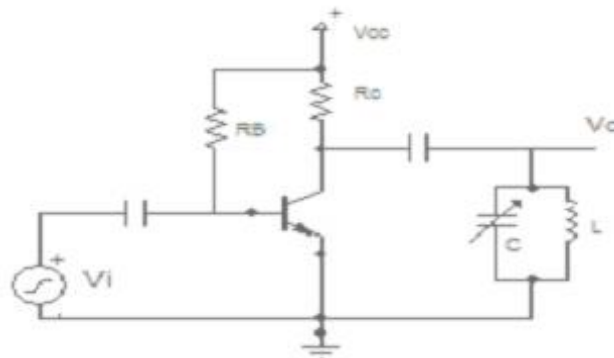


Figure 3

4. (a) Using three pin voltage regulator, design a current source that will deliver 0.25A current to 48 ohms 10W load. From data sheet $I_Q = 4.2$ mA and $V_R = 5$ V [6]
(b) Compare IC 723 and IC78XX Voltage Regulators [4]
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5. (a) Explain why voltage regulators are required for a DC power supply operating from an AC source?
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- (c) Give the differences between Load and Line Regulations. [6+4+6]
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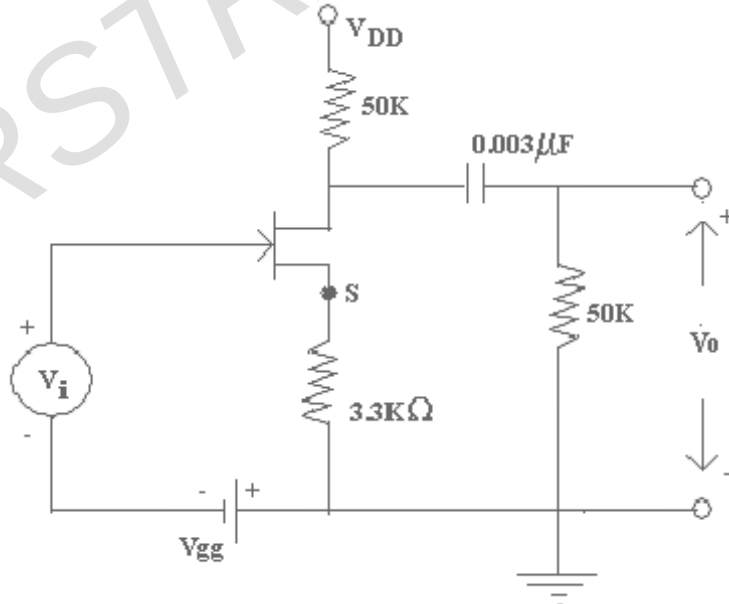


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